



**THE DATASHEET OF  
NTHD5902T1**



# NTHD5902T1

## Power MOSFET Dual N-Channel ChipFET™

2.9 Amps, 30 Volts

### Features

- Low  $R_{DS(on)}$  for Higher Efficiency
- Miniature ChipFET Surface Mount Package Saves Board Space

### Applications

- Power Management in Portable and Battery-Powered Products; i.e., Cellular and Cordless Telephones and PCMCIA Cards

### MAXIMUM RATINGS ( $T_A = 25^\circ\text{C}$ unless otherwise noted)

Rating	Symbol	5 secs	Steady State	Unit
Drain-Source Voltage	$V_{DS}$	30		V
Gate-Source Voltage	$V_{GS}$	$\pm 20$		V
Continuous Drain Current ( $T_J = 150^\circ\text{C}$ ) (Note 1) $T_A = 25^\circ\text{C}$ $T_A = 85^\circ\text{C}$	$I_D$	$\pm 3.9$ $\pm 2.8$	$\pm 2.9$ $\pm 2.1$	A
Pulsed Drain Current	$I_{DM}$	$\pm 10$		A
Continuous Source Current (Diode Conduction) (Note 1)	$I_S$	1.8	0.9	A
Maximum Power Dissipation (Note 1) $T_A = 25^\circ\text{C}$ $T_A = 85^\circ\text{C}$	$P_D$	2.1 1.1	1.1 0.6	W
Operating Junction and Storage Temperature Range	$T_J, T_{stg}$	-55 to +150		$^\circ\text{C}$

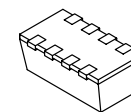
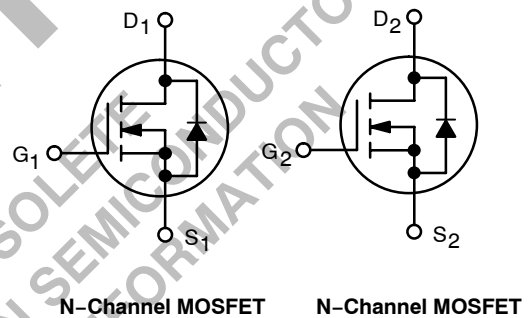
1. Surface Mounted on 1" x 1" FR4 Board.



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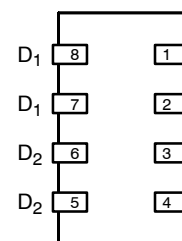
<http://onsemi.com>

**DUAL N-CHANNEL  
2.9 AMPS, 30 VOLTS  
 $R_{DS(on)} = 85 \text{ m}\Omega$**

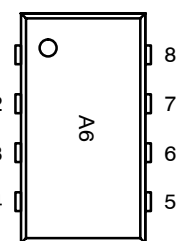


ChipFET  
CASE 1206A  
STYLE 2

### PIN CONNECTIONS



### MARKING DIAGRAM



A6 = Specific Device Code

### ORDERING INFORMATION

Device	Package	Shipping
NTHD5902T1	ChipFET	3000/Tape & Reel

# NTHD5902T1

## THERMAL CHARACTERISTICS

Characteristic	Symbol	Typ	Max	Unit
Maximum Junction-to-Ambient (Note 2) $t \leq 5$ sec Steady State	$R_{thJA}$	50 90	60 110	$^{\circ}\text{C}/\text{W}$
Maximum Junction-to-Foot Steady State	$R_{thJF}$	30	40	$^{\circ}\text{C}/\text{W}$

## ELECTRICAL CHARACTERISTICS ( $T_J = 25^{\circ}\text{C}$ unless otherwise noted)

Characteristic	Symbol	Test Condition	Min	Typ	Max	Unit
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### Static

Gate Threshold Voltage	$V_{GS(th)}$	$V_{DS} = V_{GS}, I_D = 250 \mu\text{A}$	1.0	-	-	V
Gate-Body Leakage	$I_{GSS}$	$V_{DS} = 0 \text{ V}, V_{GS} = \pm 20 \text{ V}$	-	-	$\pm 100$	nA
Zero Gate Voltage Drain Current	$I_{DSS}$	$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}$	-	-	1.0	$\mu\text{A}$
		$V_{DS} = 24 \text{ V}, V_{GS} = 0 \text{ V}, T_J = 85^{\circ}\text{C}$	-	-	5.0	
On-State Drain Current (Note 3)	$I_{D(on)}$	$V_{DS} \geq 5.0 \text{ V}, V_{GS} = 10 \text{ V}$	10	-	-	A
Drain-Source On-State Resistance (Note 3)	$r_{DS(on)}$	$V_{GS} = 10 \text{ V}, I_D = 2.9 \text{ A}$	-	0.072	0.085	$\Omega$
		$V_{GS} = 4.5 \text{ V}, I_D = 2.2 \text{ A}$	-	0.120	0.143	
Forward Transconductance (Note 3)	$g_{fs}$	$V_{DS} = 15 \text{ V}, I_D = 2.9 \text{ A}$	-	20	-	S
Diode Forward Voltage (Note 3)	$V_{SD}$	$I_S = 0.9 \text{ A}, V_{GS} = 0 \text{ V}$	-	0.8	1.2	V

### Dynamic (Note 4)

Total Gate Charge	$Q_g$	$V_{DS} = 15 \text{ V}, V_{GS} = 10 \text{ V}, I_D = 2.9 \text{ A}$	-	5.0	7.5	nC
Gate-Source Charge	$Q_{gs}$		-	0.8	-	
Gate-Drain Charge	$Q_{gd}$		-	1.0	-	
Turn-On Delay Time	$t_{d(on)}$	$V_{DD} = 15 \text{ V}, R_L = 15 \Omega, I_D \cong 1.0 \text{ A}, V_{GEN} = 10 \text{ V}, R_G = 6 \Omega$	-	7.0	11	ns
Rise Time	$t_r$		-	12	18	
Turn-Off Delay Time	$t_{d(off)}$		-	12	18	
Fall Time	$t_f$		-	7.0	11	
Source-Drain Reverse Recovery Time	$t_{rr}$	$I_F = 0.9 \text{ A}, di/dt = 100 \text{ A}/\mu\text{s}$	-	40	80	

2. Surface Mounted on 1" x 1" FR4 Board.
3. Pulse Test: Pulse Width  $\leq 300 \mu\text{s}$ , Duty Cycle  $\leq 2\%$ .
4. Guaranteed by design, not subject to production testing.

TYPICAL ELECTRICAL CHARACTERISTICS

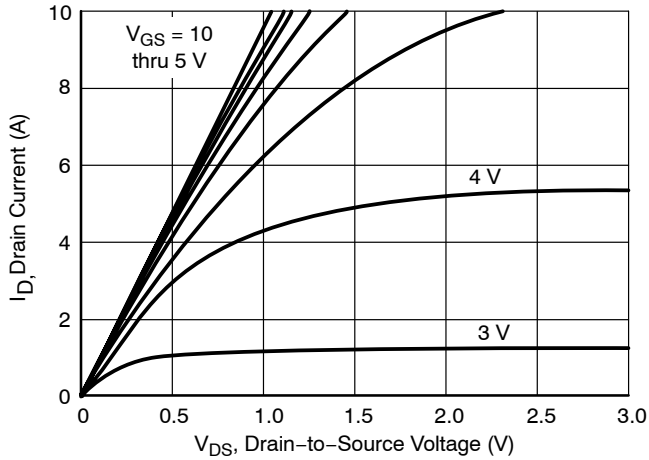


Figure 1. Output Characteristics

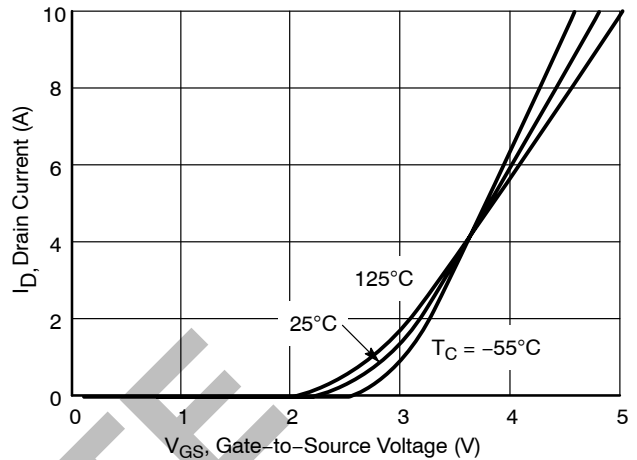


Figure 2. Transfer Characteristics

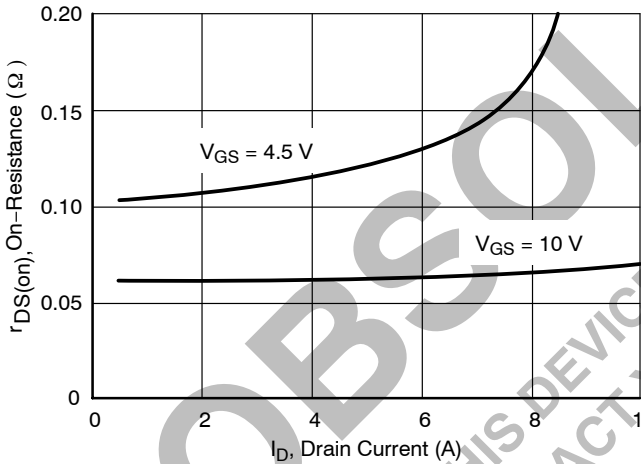


Figure 3. On-Resistance vs. Drain Current

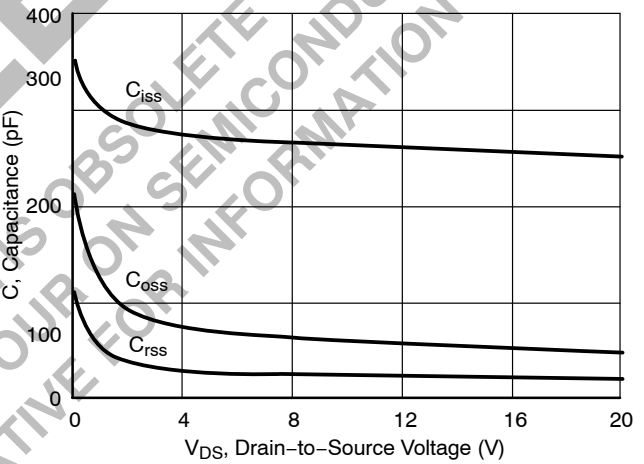


Figure 4. Capacitance

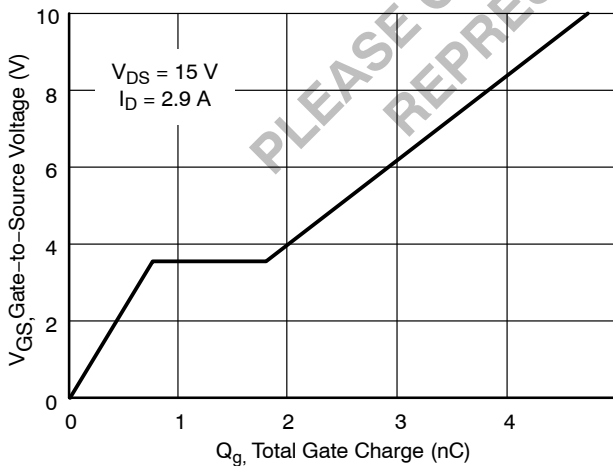


Figure 5. Gate Charge

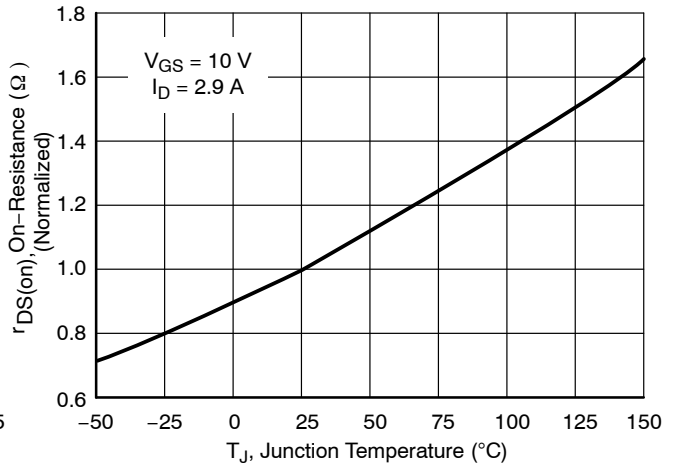


Figure 6. On-Resistance vs. Junction Temperature

TYPICAL ELECTRICAL CHARACTERISTICS

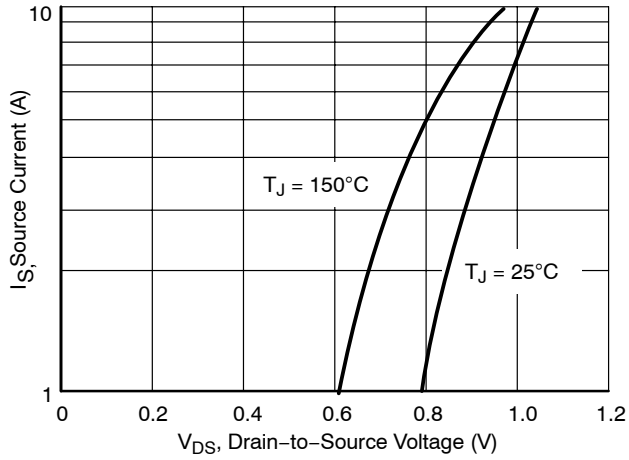


Figure 7. Source-Drain Diode Forward Voltage

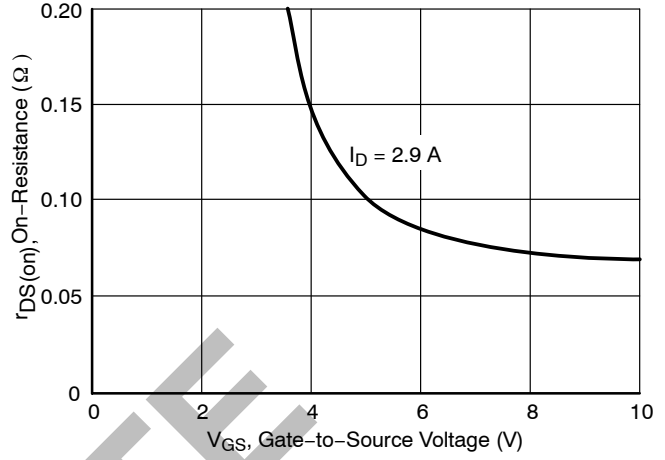


Figure 8. On-Resistance vs. Gate-to-Source Voltage

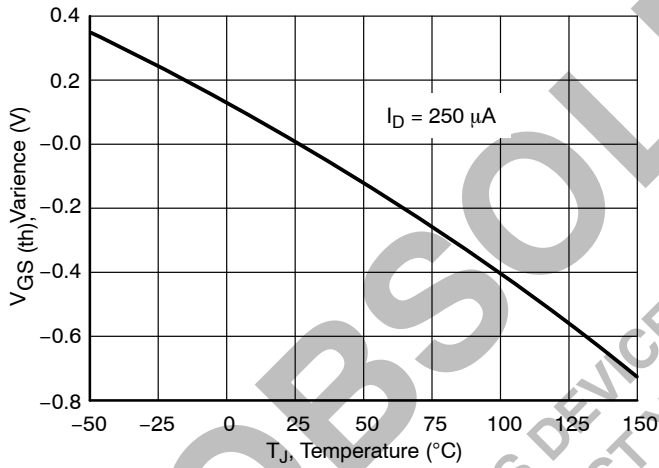


Figure 9. Threshold Voltage

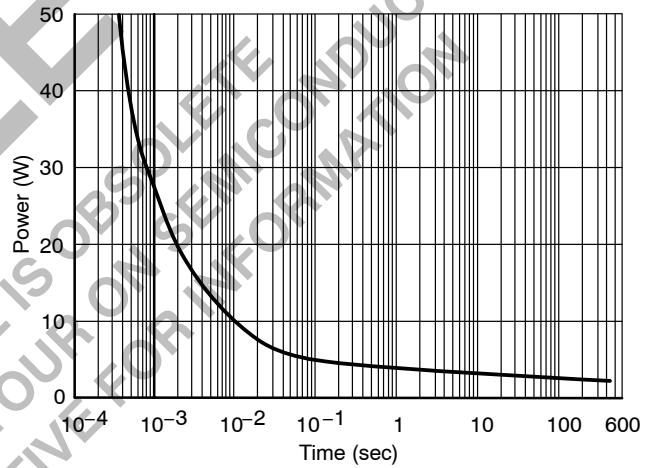


Figure 10. Single Pulse Power

TYPICAL ELECTRICAL CHARACTERISTICS

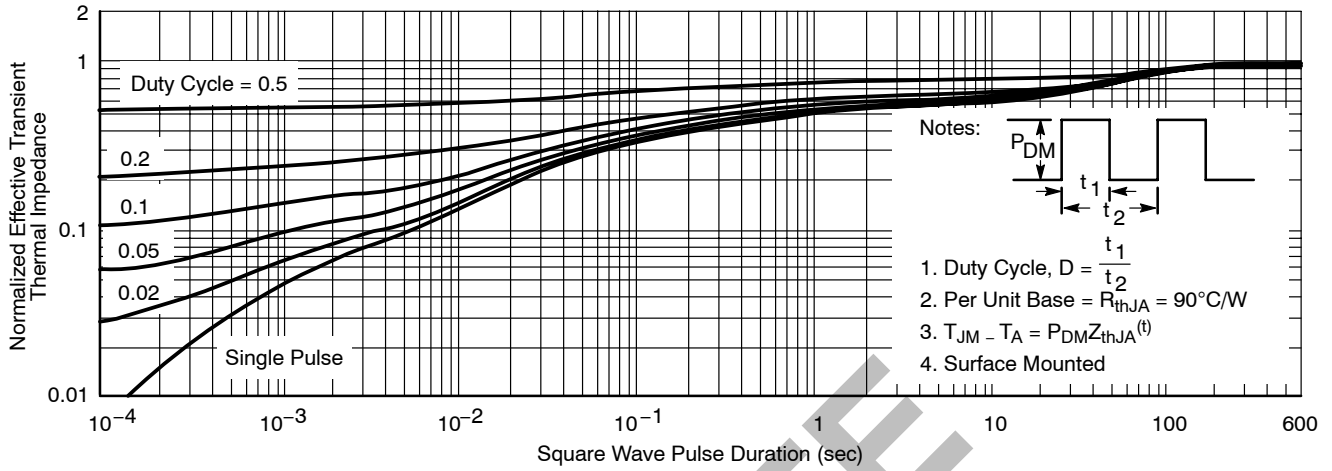


Figure 11. Normalized Thermal Transient Impedance, Junction-to-Ambient

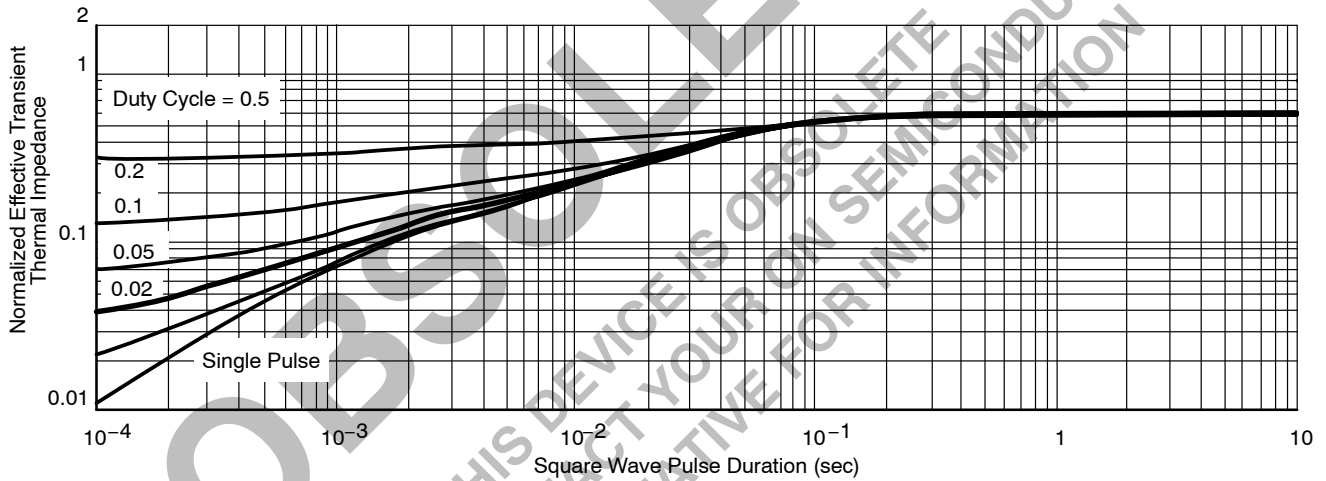


Figure 12. Normalized Thermal Transient Impedance, Junction-to-Foot

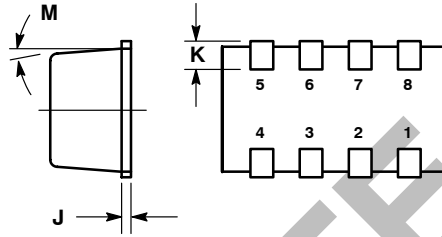
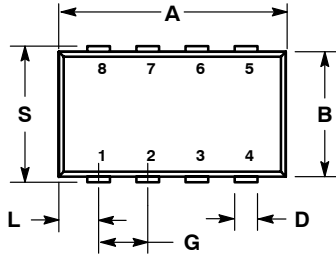
**Notes**

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# NTHD5902T1

## PACKAGE DIMENSIONS

ChipFET  
CASE 1206A-03  
ISSUE D



0.05 (0.002)

STYLE 2:

- PIN 1. SOURCE 1  
2. GATE 1  
3. SOURCE 2  
4. GATE 2  
5. DRAIN 2  
6. DRAIN 2  
7. DRAIN 1  
8. DRAIN 1

### NOTES:

- DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982.
- CONTROLLING DIMENSION: MILLIMETER.
- MOLD GATE BURRS SHALL NOT EXCEED 0.13 MM PER SIDE.
- LEADFRAME TO MOLDED BODY OFFSET IN HORIZONTAL AND VERTICAL SHALL NOT EXCEED 0.08 MM.
- DIMENSIONS A AND B EXCLUSIVE OF MOLD GATE BURRS.
- NO MOLD FLASH ALLOWED ON THE TOP AND BOTTOM LEAD SURFACE.
- 1206A-01 AND 1206A-02 OBSOLETE. NEW STANDARD IS 1206A-03.

DIM	MILLIMETERS		INCHES	
	MIN	MAX	MIN	MAX
A	2.95	3.10	0.116	0.122
B	1.55	1.70	0.061	0.067
C	1.00	1.10	0.039	0.043
D	0.25	0.35	0.010	0.014
G	0.65 BSC		0.025 BSC	
J	0.10	0.20	0.004	0.008
K	0.28	0.42	0.011	0.017
L	0.55 BSC		0.022 BSC	
M	5° NOM		5° NOM	
S	1.80	2.00	0.072	0.080


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